

DIGITRON SEMICONDUCTORS

MBR3035WT-MBR3045WT 30A SCHOTTKY RECTIFIER

MAXIMUM RATINGS

Rating	Symbol	MBR		Unit
		3035WT	3045WT	
Peak repetitive reverse voltage	V_{RRM}			
Working peak reverse voltage	V_{RWM}	35	45	V
DC blocking voltage	V_R			
Average rectified forward current (Rated V_R)	$I_{F(AV)}$	30 @ $T_C = 105^\circ C$		A
Peak repetitive forward current (Rated V_R, square wave, 20 kHz)	I_{FRM}	30		A
Peak repetitive reverse surge current (2.0μs, 1.0 kHz)	I_{RRM}	2		A
Non-repetitive peak surge current (surge applied at rated load conditions, halfwave, single phase, 60Hz)	I_{FSM}	200		A
Operating junction temperature range	T_J	-65 to +150		°C
Storage junction temperature range	T_{stg}	-65 to +175		°C
Peak surge junction temperature (forward current applied)	$T_{J(pk)}$	175		°C
Voltage rate of change (Rated V_R)	dv/dt	10		V/ns
Maximum thermal resistance				
Junction to case	$R_{\theta JC}$	1.4		°C/W
Junction to ambient	$R_{\theta JA}$	40		

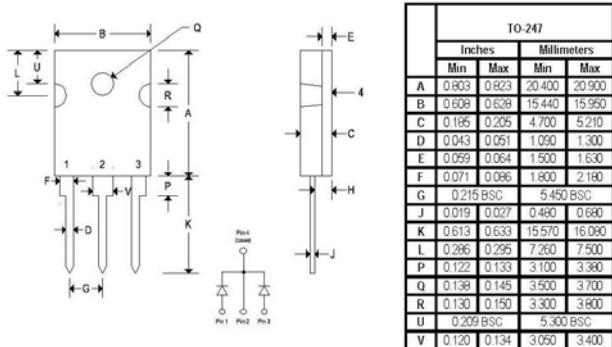
ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	MBR		Unit
		3035WT	3045WT	
Maximum instantaneous forward voltage ⁽¹⁾ ($I_F = 20A$, $T_C = 125^\circ C$) ($I_F = 30A$, $T_C = 125^\circ C$) ($I_F = 30A$, $T_C = 25^\circ C$)	V_F	0.6 0.72 0.76		V
Maximum instantaneous reverse current ⁽¹⁾ (Rated dc voltage, $T_C = 125^\circ C$) (Rated dc voltage, $T_C = 25^\circ C$)	I_R	100 1.0		mA

Note 1: Pulse test: Pulse width = 300 μ s, duty cycle \leq 2.0%.

MECHANICAL CHARACTERISTICS

Case	TO-247
Marking	Alpha-numeric
Pin out	See below



DIGITRON SEMICONDUCTORS

MBR3035WT-MBR3045WT

30A SCHOTTKY RECTIFIER

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).
Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

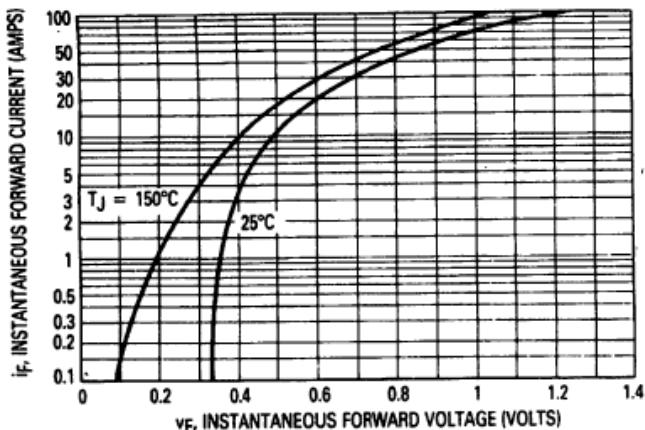


Figure 1. Typical Forward Voltage

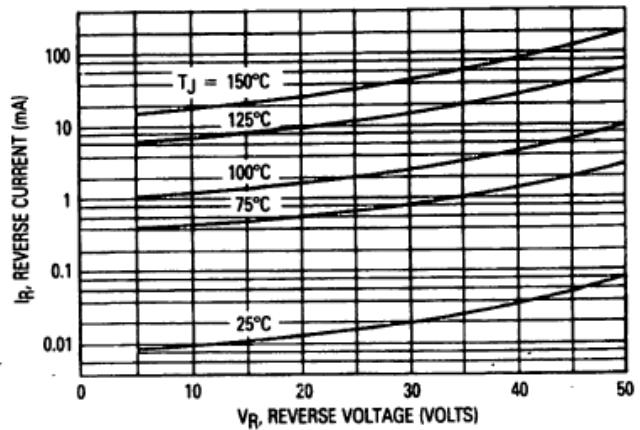


Figure 2. Typical Reverse Current

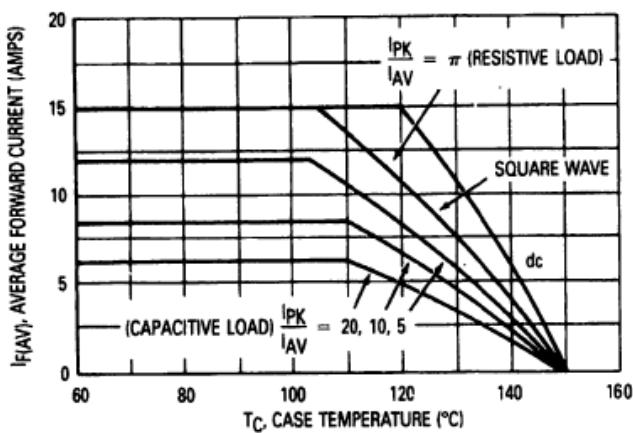


Figure 3. Current Derating (Per Leg)

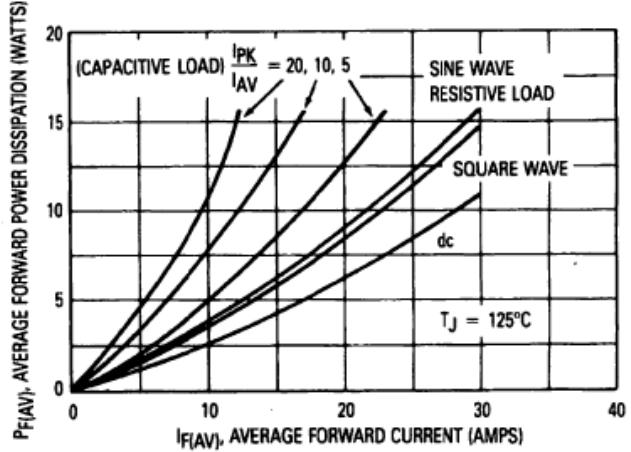


Figure 4. Forward Power Dissipation (Per Leg)

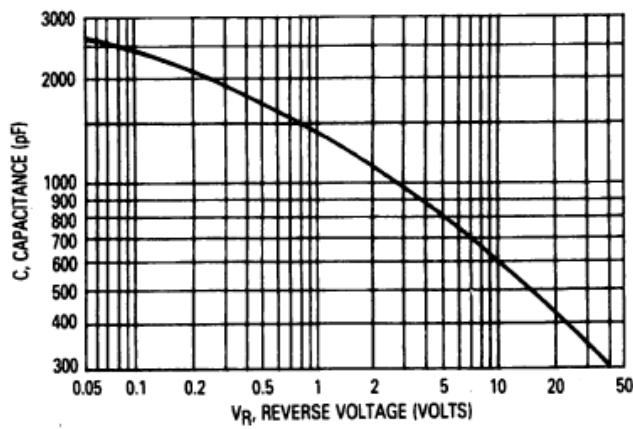


Figure 5. Capacitance

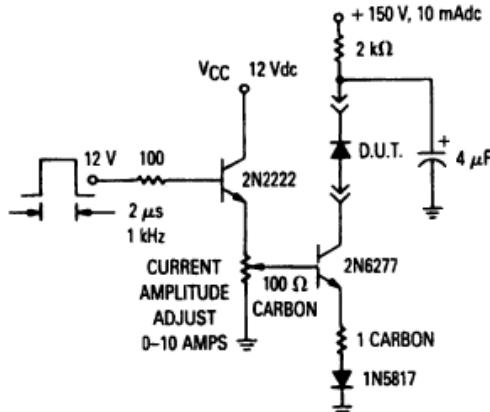


Figure 6. Test Circuit For Repetitive Reverse Current